Supplementary Information

Magnetic-field manipulation of circularly polarized photoluminescence in chiral perovskites

Ruiheng Pan,^{a,b} Kai Wang,^{a,b,*} Zhi-Gang Yu^{c,d,*}

^a Key Laboratory of Luminescence and Optical Information, Ministry of Education, School of Science, Beijing Jiaotong University, Beijing, 100044, China

^b Institute of Optoelectronics Technology, Beijing Jiaotong University, Beijing, 100044, China

° ISP/Applied Science Laboratory, Washington State University, Spokane, Washington 99210, USA

^d Department of Physics and Astronomy, Washington State University, Pullman, Washington, 99164, USA

*Corresponding authors: kaiwang@bjtu.edu.cn (Kai Wang); zhi-gang.yu@wsu.edu (Zhi-Gang Yu)





S-Fig. 1 Variation of PL intensity due to the left (σ^+) and right (σ^-) circularly polarized photoexcitation for (a) (R-MBA)₂PbI₄ and (b) (S-MBA)₂PbI₄ respectively. The photoexcitation wavelength is 405 nm and the power is set to be 90 mW.



S-Fig. 2 (a)-(f) Experimental results of temperature dependent CPL for the solution processed (R-MBA)₂PbI₄ thin film.



S-Fig. 3 (a)-(f) Experimental results of the temperature dependent CPL for the solution processed (S-MBA)₂PbI₄ thin film.



S-Fig. 4 Experimental results of temperature dependent CPL for the solution processed $(R-MBA)_2PbI_4$ thin film at 900 mT.



S-Fig. 5 (a)-(f) Experimental results of temperature dependent CPL for the solution processed (S-MBA)₂PbI₄ thin film at 900 mT.



S-Fig. 6 Experimental results of temperature dependent CPL for the solution processed $(R-MBA)_2PbI_4$ thin film at -900 mT.



S-Fig. 7 Experimental results of temperature dependent CPL for the solution processed $(S-MBA)_2PbI_4$ thin film at -900 mT.



S-Fig. 8 CPL spectra for $(R-MBA)_2PbI_4$ and $(S-MBA)_2PbI_4$ thin films measured at T = 4 K with the applications of magnetic fields at (a) 0 mT, (b) 300 mT, and (c) 700 mT respectively.

Part II - Theoretical Model

1. Exciton states

The exciton states for OIHPs have: Γ_1 (dark), Γ_2 (polarized light emission along the z-axis), and Γ_5^{\pm} (doubly degenerate, CPL emission). If we use $c \pm$ and $\bar{v} \pm$ to denote electron and hole spin states respectively, in which \pm represents the up- (\uparrow) and down- (\downarrow) components of (pseudo) spins $j_e = 1/2$ and $s_h = 1/2$. The exciton states for Γ_1 , Γ_2 , and Γ_5^{\pm} can be written as:

$$|\Gamma_{1}\rangle = \frac{1}{\sqrt{2}}(|c_{+}\bar{v}_{-}\rangle - |c_{-}\bar{v}_{+}\rangle), |\Gamma_{2}\rangle = \frac{1}{\sqrt{2}}(|c_{+}\bar{v}_{-}\rangle + |c_{-}\bar{v}_{+}\rangle), |\Gamma_{5}^{\pm}\rangle = |c_{\pm}\bar{v}_{\pm}\rangle, (S1)$$

The four possible spin configurations are $c_+ \bar{v}_+$, $c_- \bar{v}_-$, $c_+ \bar{v}_-$ and $c_- \bar{v}_+$ for an exciton. The energy states can be characterized by the total angular momentum $J = j_e + s_h$. In this case, the exciton states, Γ_1 , Γ_2 , and Γ_5^{\pm} , correspond to $|J^{ex}, J_z^{ex}\rangle = |0, 0\rangle$, $|1, 0\rangle$, and $|1, \pm\rangle$ respectively. J_z^{ex} denotes the projection of J^{ex} on the z-axis.

Note that for the conduction electrons $j_e = l + s_e$ with l = 1 and one should not be confused j_e with s_e . When discussing electron g-factors and exchange coupling, the relevant property is the pseudo spin j_e . Whereas in discussing optical selection, it is the real spin that is preserved in the electric-dipole transitions.

2. Exchange coupling

There exists a short-range exchange coupling between the electron and hole pseudo spins, the corresponding Hamiltonian (H_{ex}) for the exchange coupling can be written as:

$$H_{ex} = J_{\parallel} \sigma_{ez} \sigma_{hz} + J_{\perp} (\sigma_{ex} \sigma_{hx} + \sigma_{ey} \sigma_{hy}) \equiv J_{\parallel} \sigma_{ez} \sigma_{hz} + 2J_{\perp} (\sigma_{e} - \sigma_{h+} + \sigma_{e+} \sigma_{h-})_{, (S2)}$$

where σ_{ex} , σ_{ey} , σ_{ez} are the Pauli spin matrices of x, y and z components for electrons. σ_{hx} , σ_{hy} , σ_{hz} are the Pauli spin matrices of x, y and z components for holes. $J \parallel$ and $J \perp$ are the exchange coefficients, in parallel and perpendicular to the C-axis (tetragonal, β phase, symmetry axis of C_{4v}). It breaks the energy degeneracy among the four exciton states. Here $\sigma_{e(h)\pm} = (\sigma_{e(h)x} \pm i\sigma_{e(h)y})/2$. The exciton energies, with H_{sr} included, become,

$$E_1 = -J_{\parallel} - 2J_{\perp}, E_2 = -J_{\parallel} + 2J_{\perp}, E_5 = J_{\parallel}, (S3)$$

If $J_{\parallel} \neq J_{\perp}, E_2 \neq E_5$, i.e., there is an energy splitting between $(J,J_z) = (1,0)$ and $(1, \pm 1)$.

3. Zeeman energy

In the presence of a magnetic field **B**, the Hamiltonian associated Zeeman energy (H_Z) can be written as:

$$H_{Z} = \frac{1}{2} \mu_{B} [g_{e \perp} (\sigma_{ex} B_{x} + \sigma_{ey} B_{y}) + g_{e \parallel} \sigma_{ex} B_{z} + g_{h \perp} (\sigma_{hx} B_{x} + \sigma_{hy} B_{y}) + g_{h \parallel} \sigma_{hz} B_{z}],$$
(S4)

in which, μ_B is the Bohr magneton. It is known that a free electron has only the intrinsic spin magnetic moment with a g-factor of approximately 2.0023. The orbital motion of the electron can create an additional magnetic moment and couple with the spin moment. Eventually, it yields an effective g-factor. H_Z has taken into account the anisotropic g-factors for the electron and hole. In equation S4, $g_{e\perp}$ and $g_{e\parallel}$ denote the g-factor of the conduction band-edge in perpendicular and parallel to the C-axis respectively; while, $g_{h\perp}$ and $g_{h\parallel}$ denote the g-factor of the valence band-edge in perpendicular and parallel to the C-axis respectively. For a magnetic field having an angle θ with respect to the crystallographic axis, the measured g-factors for an electron or hole $(g_{e(h)})$ should be expressed as:

$$g_{e(h)}(\theta) = (g_{e(h)\parallel} \cos^2 \theta + g_{e(h)\perp} \sin^2 \theta)^{1/2}, \text{ equation (S5)}$$

By using the basis set $(\Gamma_5^+, \Gamma_5^+, \Gamma_1, \Gamma_2)$, we can write $H_{ex} + H_Z$ as:

$$\begin{split} H_{ex} + H_{Z} & 0 & \frac{\mu_{B}}{2\sqrt{2}}(g_{h\perp} - g_{e\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\parallel} + g_{h\parallel})B_{z} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} - g_{e\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} + g_{e\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} - g_{h\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} - g_{h\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} - g_{h\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\perp} - g_{h\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\parallel} - g_{h\perp})B_{\perp} & \frac{\mu_{B}}{2\sqrt{2}}(g_{e\parallel} - g_{h\parallel})B_{\perp} & \frac{\mu_{B}}{2}(g_{e\parallel} - g_{h\parallel})B_{\perp} & \frac$$

(S6)

where $B_{\pm} = B_x + iB_y$.

We can write the effective Hamiltonian (\hat{H}) between Γ_5^+ and Γ_5^- as:

$$\tilde{H} = \begin{pmatrix} \frac{\Delta E}{2} + \frac{\mu_B}{2} (g_{e\parallel} + g_{h\parallel}) B_z & \gamma B_-^2 \\ \gamma B_+^2 & -\frac{\Delta E}{2} - \frac{\mu_B}{2} (g_{e\parallel} + g_{h\parallel}) B_z \end{pmatrix},$$
(S7)

where,

$$\gamma = \frac{1}{16} \mu_B^2 \left[\frac{(g_{e\perp} + g_{h\perp})^2}{J_{\parallel} - J_{\perp}} - \frac{(g_{e\perp} - g_{h\perp})^2}{J_{\parallel} + J_{\perp}} \right], (S8)$$

$$\hat{\rho} = \sum_{\pm} \rho_{\pm,\pm} |\Gamma_{\pm}^{\pm}\rangle \langle \Gamma_{\pm}^{\pm}|$$

Again we solve the Bloch equation of the density matrix

$$\frac{\partial \hat{\rho}}{\partial t} = \frac{i}{\hbar} [\rho, \tilde{H}] + \left(\frac{\partial \hat{\rho}}{\partial t}\right)_g - \frac{\hat{\rho}}{\tau} - \left(\frac{\partial \hat{\rho}}{\partial t}\right)_{sr} (S9)$$

Here we have explicitly included spin relaxation, which can be described by T_1 and T_2 ,

$$\left(\frac{\partial(\rho_{++} - \rho_{--})}{\partial t}\right)_{sr} = -\frac{\rho_{++} - \rho_{--}}{T_1}, (S10)$$
$$\left(\frac{\partial\rho_{+-}}{\partial t}\right)_{sr} = -\frac{\rho_{+-}}{T_2}, (S11)$$

4. Optical selection rules

The optical selection rules of these exciton states can be derived from the matrix elements of the momentum operator, $e \cdot p$ with e being the electric-field polarization of the electromagnetic wave. According to the effective-mass model, we have,

$$\langle \Gamma_{1} | e \cdot p | G \rangle = 0, \text{ (S12)}$$
$$\langle \Gamma_{2} | e \cdot p | G \rangle = i \frac{m}{\hbar} sin\xi P_{\parallel} e_{z}, \text{ (S13)}$$
$$\langle \Gamma_{5}^{\pm} | e \cdot p | G \rangle = i \frac{m}{\hbar} cos\xi P_{\perp} e_{\pm}, \text{ (S14)}$$

where m is the free-electron mass, $P \parallel$ and $P \perp$ and are the Kane parameters.

5. Orientation average

For a tilted angle θ , a right circularly polarized emission has both right and left circularly polarized components, with amplitudes:

$$p_{\pm} \equiv \left(\frac{1 \pm \cos \theta}{2}\right)^2_{,\,(S15)}$$

Thus the circular polarization degree is:

$$P_{c} = \frac{\left(I_{L}^{0}p_{+} + I_{R}^{0}p_{-}\right) - \left(I_{L}^{0}p_{-} + I_{R}^{0}p_{+}\right)}{\left(I_{L}^{0}p_{+} + I_{R}^{0}p_{-}\right) + \left(I_{L}^{0}p_{-} + I_{R}^{0}p_{+}\right)} = \frac{\cos\theta}{1 + \cos^{2}\theta I_{L}^{0} + I_{R}^{0}} = \frac{\cos\theta}{1 + \cos^{2}\theta} \tan h \frac{\Delta E + g_{ex}\mu_{B}B\cos\theta}{2\kappa_{B}T},$$
(S16)

We perform the orientation average:

$$P_{c} = \int_{0}^{\pi/2} d\theta \sin \theta \frac{\cos \theta \quad \Delta E + g_{ex} \mu_{B} B \cos \theta}{1 + COS^{2} \theta \quad 2\kappa_{B} T},$$
(S17)
$$P_{c} = \frac{1}{2\kappa_{B} T} \left[\Delta E \frac{\log 2}{2} + g_{ex} \mu_{B} B \left(1 - \frac{\pi}{4} \right) \right],$$
(S18)

Thus the Hamiltonian for Γ_2 and Γ_{5x} is:

$$H' = H_{ex} + H_Z = \begin{pmatrix} -J_{\parallel} + 2J_{\perp} & i(g_{e\perp} + g_{h\perp})\mu_B B_x/2 \\ -i(g_{e\perp} + g_{h\perp})\mu_B B_x/2 & J_{\parallel} \end{pmatrix},$$
(S19)

Population dynamics can be obtained by solving the Bloch equation of the density matrix.

$$\frac{\partial \hat{\rho}}{\partial t} = \frac{i}{\hbar} [\rho, H'] + \left(\frac{\partial \hat{\rho}}{\partial t}\right)_g - \frac{\hat{\rho}}{\tau}, \quad (S20)$$

where $\hat{\rho}$ is a 2×2 density matrix spanned by Γ_2 and Γ_{5x} , $\hat{\rho} = \sum_{m,n} \rho_{mn} |\psi_m\rangle \langle \psi_n|$ with m,n = 1, 2 and $\psi_{1(2)} = \Gamma_{2(5x)} \cdot (\partial \rho / \partial t)_g$ represents the generation of the

exciton states, which is finite only for diagonal terms, $(\partial \rho_{mn}/\partial t)_g = F_m \delta_{mn}$, because the PL in the MFE measurements is not resonantly excited. τ is the recombination life time of these exciton states.